CHIPLED®

Silicon NPN Phototransistor









Applications

- Electronic Equipment
- Industrial Automation (Machine Controls, Light Barriers, Vision Controls)
- Touch Screens
- Touch Screens, Gesture Recognition

Features:

- Package: black epoxy

- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)

- Spectral range of sensitivity: (typ) 770 ... 1090 nm

- Narrow half angle (± 13°)

- Low profile sidelooker (1.6mm)

- Emitter in similar package available: SFH 4045N

Ordering Information

Type Photocurrent ¹) Photocurrent ²) Ordering Code typ. $V_{CE} = 5 \text{ V; } \lambda = 950 \text{ nm; } E_e = 0.1 \text{ mW/} V_{CE} = 5 \text{ V; } \lambda = 950 \text{ nm; } E_e = 0.1 \text{ mW/cm}^2 V_{CE} = 5 \text{ V; } \lambda = 950 \text{ nm; } E_e = 0.1 \text{ mW/cm}^2 V_{CE} = 5 \text{ V; } \lambda = 950 \text{ nm; } E_e = 0.1 \text{ mW/cm}^2 V_{CE} = 5 \text{ V; } \lambda = 950 \text{ nm; } E_e = 0.1 \text{ mW/cm}^2 V_{CE} = 5 \text{ V; } \lambda = 950 \text{ nm; } E_e = 0.1 \text{ mW/cm}^2 V_{CE} = 5 \text{ V; } \lambda = 950 \text{ nm; } E_e = 0.1 \text{ mW/cm}^2 V_{CE} = 5 \text{ V; } \lambda = 950 \text{ nm; } E_e = 0.1 \text{ mW/cm}^2 V_{CE} = 5 \text{ V; } \lambda = 950 \text{ nm; } E_e = 0.1 \text{ mW/cm}^2 V_{CE} = 5 \text{ V; } \lambda = 950 \text{ nm; } E_e = 0.1 \text{ mW/cm}^2 V_{CE} = 5 \text{ V; } \lambda = 950 \text{ nm; } E_e = 0.1 \text{ mW/cm}^2 V_{CE} = 0.1 \text{ mW/cm}^2 V_{$

Only one bin within one packing unit (variation less than 2:1)



Maximum	Ratings
IVIAAIIIIUIII	Raungs

T.	=	25	$^{\circ}C$
Ι,	_	20	\circ

Parameter	Symbol		Values
Operating temperature	T _{op}	min. max.	-25 °C 85 °C
Storage temperature	T _{stg}	min. max.	-40 °C 85 °C
Collector-emitter voltage	V _{CE}	max.	15 V
Collector-emitter voltage pulse $t \le 10 \ \mu s; T_A = 25 \ ^{\circ}C$	V _{CE pulse}	max.	30 V
Collector current	I _c	max.	15 mA
Collector surge current T ≤ 10 µs	I _{cs}	max.	75 mA
Emitter-collector voltage	$V_{\sf EC}$	max.	7 V
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)	V_{ESD}	max.	2 kV



Characteristics

T_A = 25 °C

Parameter	Symbol		Values
Wavelength of max sensitivity	$\lambda_{_{ extsf{S max}}}$	typ.	870 nm
Spectral range of sensitivity	\(\lambda_{10\%}\)	typ.	770 1090 nm
Dimensions of chip area	LxW	typ.	0.35 x 0.35 mm x mm
Radiant sensitive area	А	typ.	0.04 mm²
Half angle	φ	typ.	13 °
Rise time $I_C = 1 \text{ mA}$; $\lambda = 950 \text{ nm}$; $V_{CE} = 5 \text{ V}$; $R_L = 1 \text{ k}\Omega$	t _r	typ.	7 µs
Fall time $I_C = 1 \text{ mA}$; $\lambda = 950 \text{ nm}$; $V_{CE} = 5 \text{ V}$; $R_L = 1 \text{ k}\Omega$	t _f	typ.	7 µs
Collector-emitter saturation voltage $^{3)}$ $I_{\rm C} = I_{\rm PCE,min} \times 0.3$; $E_{\rm e} = 0.1 \rm mW/cm^2$	V _{CEsat}	typ.	170 mV
Capacitance $V_{CE} = 0 \text{ V}; f = 1 \text{ MHz}; E = 0$	C_{CE}	typ.	2.4 pF



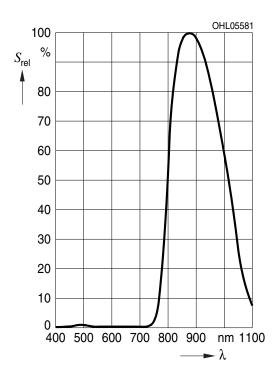
Photocurrent Groups

T_A = 25 °C

Group	Photocurrent ¹⁾ $V_{CE} = 5 \text{ V}; \lambda = 950 \text{ nm}; E_{e} = 0.1 \text{ mW/cm}^{2}$ min. I_{PCE}	Photocurrent ¹⁾ $V_{CE} = 5 \text{ V}; \lambda = 950 \text{ nm}; E_e = 0.1 \text{ mW/cm}^2 \text{ max.}$ I_{PCE}
2	180 μΑ	280 μΑ
3	280 μΑ	450 μΑ
4	450 μΑ	710 μΑ

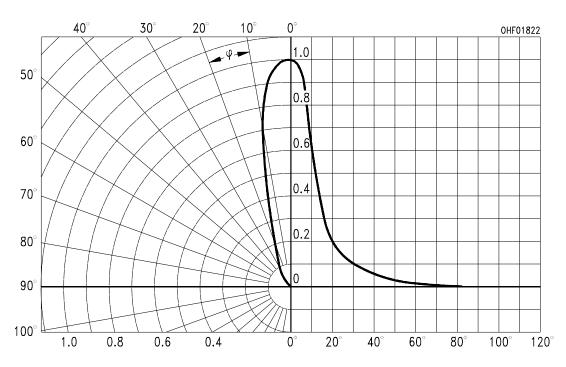
Relative Spectral Sensitivity 4), 5)

$$S_{rel} = f(\lambda)$$



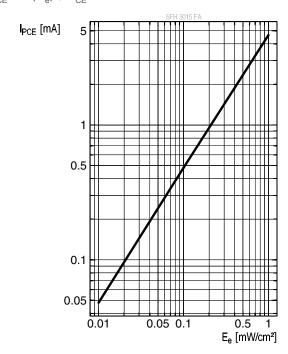
Directional Characteristics 4), 5)

$$S_{rel} = f(\phi)$$



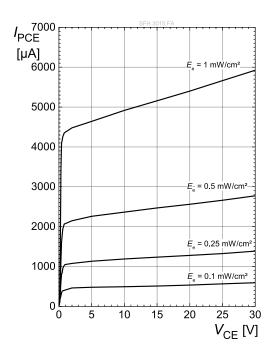
Photocurrent 4), 5)

$$I_{PCE} = f(E_e)$$
; $V_{CE} = 5 V$



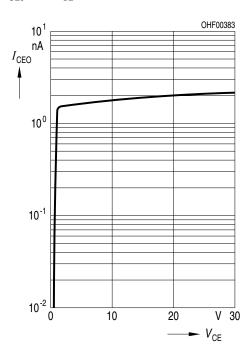
Photocurrent 4), 5)

$$I_{PCE} = f(V_{CE}); E_e = Parameter$$



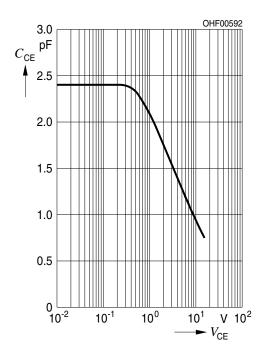
Dark Current 4), 5)

$$I_{CE0} = f(V_{CE})$$
; $E = 0$



Collector-Emitter Capacitance 4), 5)

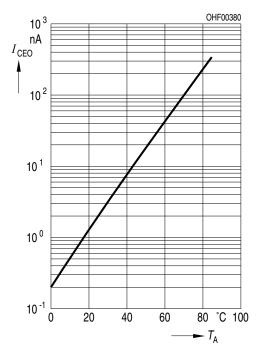
$$C_{CE} = f(V_{CE}); f = 1 MHz; E = 0$$





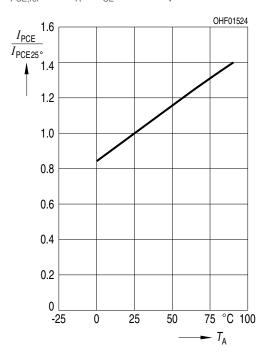
Dark Current 4)

$$I_{_{\mathrm{CE0}}}$$
 = f ($T_{_{\mathrm{A}}}$); $V_{_{\mathrm{CE}}}$ = 0 V; E = 0 ; $E_{_{\mathrm{e}}}$ = 0 mW/cm²; 0

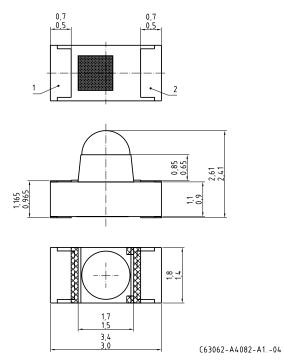


Photocurrent 4)

$$I_{PCE,rel} = f(T_A); V_{CE} = 5 V; E_v = 0 Ix$$



Dimensional Drawing 6)



Further Information:

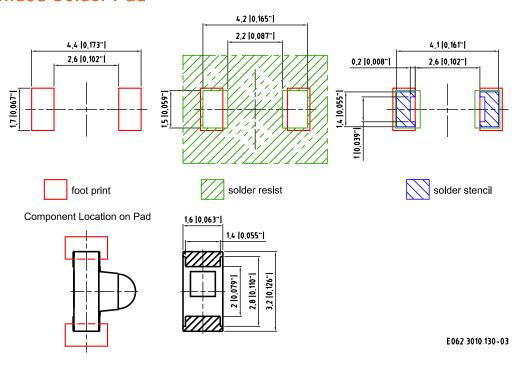
Approximate Weight: 14.0 mg **Package marking:** Collector

Pin Description

1 Emitter

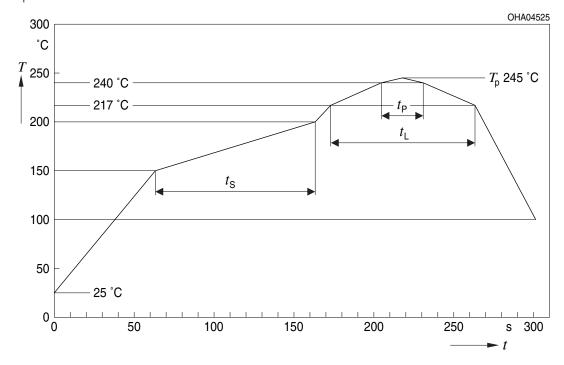
2 Collector

Recommended Solder Pad 6)



Reflow Soldering Profile

Product complies to MSL Level 3 acc. to JEDEC J-STD-020E

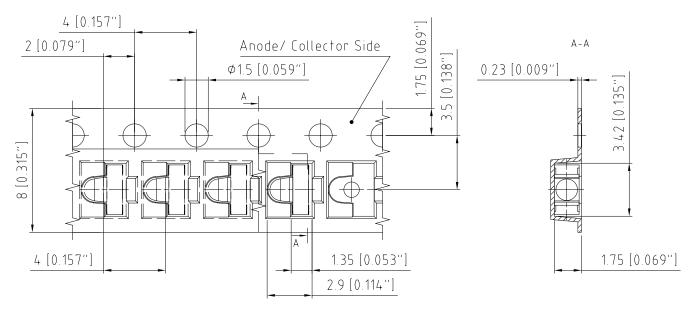




Profile Feature	Symbol	Pb	Pb-Free (SnAgCu) Assembly		
	·	Minimum	Recommendation	Maximum	
Ramp-up rate to preheat*) 25 °C to 150 °C			2	3	K/s
Time t_S T_{Smin} to T_{Smax}	t _s	60	100	120	S
Ramp-up rate to peak*) T _{Smax} to T _P			2	3	K/s
Liquidus temperature	T_{L}		217		°C
Time above liquidus temperature	t _L		80	100	S
Peak temperature	T _P		245	260	°C
Time within 5 °C of the specified peak temperature T _P - 5 K	t _P	10	20	30	S
Ramp-down rate* T _P to 100 °C			3	6	K/s
Time 25 °C to T _P				480	S

All temperatures refer to the center of the package, measured on the top of the component * slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range

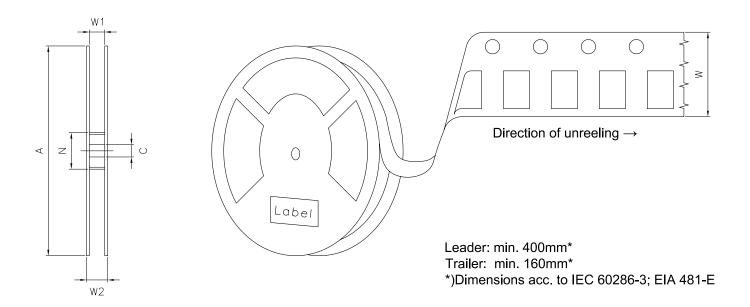
Taping 6)



C63062-A4082-B1-02



Tape and Reel 7)



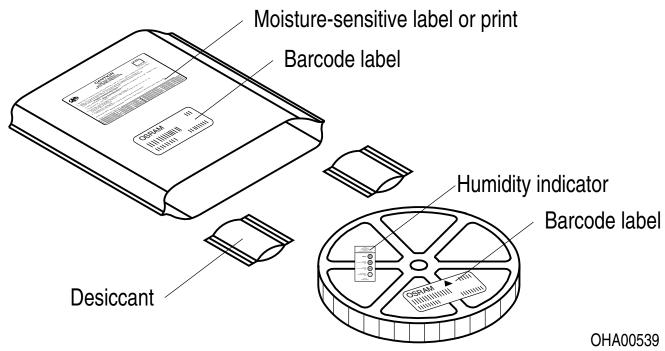
Reel Dimensions

Α	W	N_{\min}	W_1	$W_{2 \text{ max}}$	Pieces per PU
180 mm	8 + 0.3 / - 0.1 mm	60 mm	8.4 + 2 mm	14.4 mm	1500

Barcode-Product-Label (BPL)



Dry Packing Process and Materials 6)



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.



Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet falls into the class **exempt group (exposure time 10000 s)**. Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit www.osram-os.com/appnotes



Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

OSRAM OS products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using OSRAM OS components in product safety devices/applications or medical devices/applications, buyer and/or customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and buyer and /or customer will analyze and coordinate the customer-specific request between OSRAM OS and buyer and/or customer.



Glossary

- Photocurrent: The photocurrent values are measured (by irradiating the devices with a homogenous light source and applying a voltage to the device) with a tolerance of ±11 %.
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- 3) **IPCEmin:** IPCEmin is the min. photocurrent of the specified group.
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- ⁵⁾ **Testing temperature:** TA = 25°C (unless otherwise specified)
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- ⁷⁾ **Tape and Reel:** All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.



Revision History			
Version	Date	Change	
1.5	2019-07-11	Electro - Optical Characteristics (Diagrams)	
1.6	2020-11-20	Schematic Transportation Box Dimensions of Transportation Box Electro - Optical Characteristics (Diagrams)	



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